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MI DR	SHEET     1     2     3     4     5     6     7     8     9     10     11     12     1       PMIC N/A     PREPARED BY     DEFENSE I       STANDARDIZED     CHECKED BY     DEFENSE I       MILITARY     DRAWING     APPROVED BY     MICROCIRCUIT, LOW POWER SCH TRANSCE I VERS THREE-STATE A MONOLITHIC SI							E ELE DA F, D CHOT S AN AND	ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444 , DIGITAL, BIPOLAR, ADVANCED HOTTKY TIL, OCTAL BUS AND REGISTERS, WITH INVERTING AND REGISTERS, WITH INVERTING AND REGISTERS, WITH INVERTING						NG										
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DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

5962-E1738

1. SCOPE 1.1 <u>Scope</u>. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices". 1.2 Part or Identifying Number (PIN). The complete PIN shall be as shown in the following example: 5962-89687 01 Drawing number Device type Case outline Lead finish per (1.2.1)(1.2.2)MIL-M-38510 1.2.1 Device type. The device type shall identify the circuit function as follows: Device type Generic number Circuit function 01 54ALS653 Octal bus transceivers and registers with inverting three-state and open-collector outputs 1.2.2 Case outlines. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows: Outline letter Case outline F-6 (24-lead, .640" x .420" x .090"), flat package D-9 (24-lead, 1.280" x .310" x .200"), dual-in-line package C-4 (28-terminal, .460" x .460" x .100"), square chip carrier package Κ L 3 1.3 Absolute maximum ratings. -0.5 V dc to +7.0 V dc DC input voltage: -1.2 V dc at -18 mA to +7.0 V dc -1.2 V dc at -18 mA to +5.5 V dc -65 °C to +150 °C 484 mW +300°C Thermal resistance, junction-to-case  $(\theta_{JC})$  - - - - -See MIL-M-38510, appendix C +175°C 1/ Maximum power dissipation is defined as V<sub>CC</sub> x I<sub>CC</sub>, and must withstand the added P<sub>D</sub> due to short-circuit output test; e.g., I0. **STANDARDIZED** SIZE Α MILITARY DRAWING 5962-89687 DEFENSE ELECTRONICS SUPPLY CENTER **REVISION LEVEL** SHEET DAYTON, OHIO 45444 А 2 DESC FORM 193A SEP 87 ★ U.S. GOVERNMEN1 PRINTING OFFICE 1990 750 5278 查询 59.62-Recommended o 提出的 conditions.

+4.5 V dc to +5.5 V dc 2.0 V dc Maximum low\_level input voltage ( $V_{IL}$ ): 0.7 V dc 0.8 V dc 0.8 V dc Maximum high level output voltage (V<sub>OH</sub>) A ports - - -5.5 V dc Maximum high level output current ( $I_{OH}$ ) B ports - - --12 mA +12 mA -55°C to +125°C Minimum setup time, before CAB or before CBA (t<sub>s</sub>) 2/-Minimum hold time, after CAB or after CBA (t<sub>h</sub>) 2/-15.0 ns 5.0 ns Minimum pulse duration  $(t_w)$ : 25.0 ns 25.0 ns Maximum clock frequency (fclock): A output -`- -12.5 MHz - - - - - - - - -B output - - -- - - - -25 MHz 2. APPLICABLE DOCUMENTS 2.1 <u>Government specification, standard, and bulletin</u>. Unless otherwise specified, the following specification, standard, and bulletin of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein. SPECIFICATION MILITARY MIL-M-38510 Microcircuits, General Specification for. STANDARD MILITARY MIL-STD-883 - Test Methods and Procedures for Microelectronics. BULLETIN MIL ITARY MIL-BUL-103 - List of Standarized Military Drawings (SMD's). (Copies of the specification, standard, and bulletin required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.) 2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence. P/ Transition of clock from high to low. STANDARDIZED SIZE Α 5962-89687 MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER **REVISION LEVEL** SHEET DAY FON, OHIO 45444 3 DESC FORM 193A U S GOVERNMENT PRINTING OFFICE, 1985-749-033 SEP 87

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.

3.2.1 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 1.

3.2.2 Truth table. The truth table shall be as specified on figure 2.

3.2.3 Test circuits and switching waveforms. The test circuits and switching waveforms shall be as specified on figure 3.

3.2.4 <u>Case outlines</u>. The case outlines shall be in accordance with 1.2.2 herein.

3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.

3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

3.5 <u>Marking</u>. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103 (see 6.6 herein).

3.6 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.6 herein). The certificate of compliance submitted to DESC-ECC prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change. Notification of change to DESC-ECC shall be required in accordance with MIL-STD-883 (see 3.1 herein).

3.9 <u>Verification and review</u>. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

STANDARDIZED MILITARY DRAWING	size A		2-89687		
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		<b>REVISION LEVEL</b>		SHEET	4
DECC FORM 1024					

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★ U.S. GOVERNMENT PRINTING OFFICE: 1990-750-527R

# 查询 5962-8867701XA "供应南<sub>BLE I</sub>. Electrical performance characteristics

Test	Symbol	1	Conc	litions	°o • /	Group A		nits	Unit
		 	55°C < T <sub>C</sub> ess other	< +12 wise s	ocified	subgroups	Min	Max	
High level output voltage B ports	v <sub>он</sub>	$\begin{vmatrix} V_{CC} = 4. \\ V_{IH} = 2. \end{vmatrix}$		= 0.8	$I_{OH} = -0.4 \text{ mA}$ $I_{OH} = -3.0 \text{ mA}$ $I_{OH} = -12 \text{ mA}$	1,3	2.5 2.4 2.0		۷
			۷ <sub>IL</sub>	= 0.7	I <sub>OH</sub> = -0.4 mA I <sub>OH</sub> = -3.0 mA I <sub>OH</sub> = -12 mA	2	2.5 2.4 2.0		-
Low level output voltage	V <sub>OL</sub>	V <sub>CC</sub> = 4. V <sub>IH</sub> = 2. I <sub>OL</sub> = 12	5 V   D V  V <sub>IL</sub> mA	= 0.8	٧	1,3		0.4	v
		<u>2/</u>	VIL	= 0.7	۷	2		0.4	
Input clamp voltage	VIC	V <sub>CC</sub> = 4.5	5 V, I <sub>IN</sub>	= -18 m	A	1,2,3		-1.2	v
High level input current	I IH1	$V_{CC} = 5.9$	5 V	V <sub>IN</sub> = Contr	7.0 V ol inputs	1,2,3		0.1	mA
		1		V <sub>IN</sub> = A or	5.5 V B ports			0.1	
	I IH2			V <sub>IN</sub> = Contr	2.7 V ol inputs	-	<del></del>	20	μ <b>A</b>
	-			V <sub>IN</sub> = A or	2.7 V B ports			20	
ow level input current	IIL	$V_{\rm CC} = \frac{5.5}{3}$	i V	V <sub>IN =</sub> Contr	0.4 V ol inputs	1,2,3		-0.2	mA
				V <sub>IN</sub> = A or	0.4 V B ports			-0.2	
ow level output current	Іон	V <sub>CC</sub> = 4.5 V <sub>OH</sub> = 5.5	V V	A por	t   	1,2,3		0.1	mA
Dutput current		V <sub>CC =</sub> 5.5 V <sub>OUT</sub> = 2.		B por	ts	1,2,3	- 30	-112	mA
e footnotes at end o	f table.							L	
STANDARI MILITARY DI		<u>.</u>	SIZE A			5962.	-89687		
DEFENSE ELECTRONIC			5962-89687 REVISION LEVEL SHEET				 т		

U.S. GOVERNMENT PRINTING OFFICE, 1989- 749-033

Test	Symbol		Condi 55°C <u>&lt;</u> ⊺ <sub>C</sub>	tions	°C 17	Group A  subgroups	Limi	its	Unit
	<u></u>	unl	ess otherw	ise spe	ecified		Min	Max	1
Supply current	I CCH	V <sub>CC</sub> = 5.	5 V	Outpi	ıts high	1,2,3		76	mA
	ICCL			  Outpu	its low			88	
· · · · · · · · · · · · · · · · · · ·	Iccz			Outpu	its disabled			88	-   } 
Functional tests	1	See 4.3.	lc <u>5</u> /			7,8			
Maximum frequency	fmax	$V_{CC} = 4.1$ $C_{L} = 50$	5 to 5.5 V pF	dc	A output	9,10,11	12.5		MHz
	·	$ R_1 = R_2$  See figur	= <b>500</b> Ω	<u> </u>	B output		25		<u> </u>
Propagation delay time, CBA to A	tpLH1 	<u>6</u> ,		9,10,11	16	71	ns		
	t <sub>PHL1</sub>				_		6	24	1   
Propagation delay time, CAB to B	tpLH2					9,10,11	10	35	ns
	t <sub>PHL2</sub>						5	20	
Propagation delay time, A to B	tpLH3				-	9,10,11	5	20	ns
	t <sub>PHL3</sub>	   1					1.5	18	1
Propagation delay time, B to A	tp <sub>LH4</sub>	T I I				9,10,11	8	63	ns
· · · · · · · · · · · · · · · · · · ·	tpHL4	   					2	18	
Propagation delay time, SBA to A	tPLH5	T   				9,10,11	12	68	ns
(with B low) <u>7</u> /	tphl5	   			1		5	27	
ee footnotes at end									
STANDAF MILITARY D		2	SIZE A			5962-	89687		
DEFENSE ELECTRON	-			L	REVISION LEVE				

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Test	Symbol		Condi	tions	•~ • •		Group A		its	   Uni
		  un]e	55°C <u>&lt;</u> T <sub>C</sub> ess otherw	< +125 ise sp	C <u>1</u> / ecified		subgroups 	Min	Max	
Propagation delay time, SBA to A	t <sub>PLH6</sub>	ICi = 50 I	5 to 5.5 V pF	dc			9,10,11	19	68	n
(with B high) <u>7</u> /	tphl6	R1 = R2  See figur	= 500Ω re 3 <u>6</u> /			-		5	   27 	
Propagation delay time, SAB to B	t <sub>PLH7</sub>						   9,10,11 	12	40	n
(with A low) <u>7</u> /	t <sub>PHL7</sub>						   	6	25	   
Propagation delay time, SAB to B	t <sub>PLH8</sub>					-	9,10,11	8	30	n
(with A high) <u>7</u> /	t <sub>PHL8</sub>							6	25	-   
Propagation delay time, GBA to A	t <sub>PLH9</sub>						9,10,11	6	35	ns
	t <sub>PHL9</sub>							6	27	
Output enable time, GAB to B	t <sub>PZH1</sub>					ך ן ן	9,10,11	7	25	l 1 ns
	t <sub>PZL1</sub>	_				   		6	25	
Output disable time, GAB to B	t <sub>PHZ1</sub>					T I I	9,10,11	1	16	ns
	  tpLZ1					   		2	21	   
Unused inputs that No unused inputs sh All outputs must be produces the proper VIL maximum or VIH For I/O ports, the The output conditio of the true short c time and duration o Functional tests sh and VOH $\leq$ VIH $\leq$ VCC Propagation delay 1 These input paramet opposite to that of	all exceed tested. state, th minimum in parameters ns have be ircuit out f the test all be con imits are ers are me	5.5 V or In the ca e test mu put. IIH2 and en chosen put curre conditio ducted at based on asured wi	go less f se where c st be perf IIL inclu to produc nt, IOS. n shall nc input tes single out	han O. nly on ormed de the e a cu Not mo t exce t cond put sw	0 V. No e input with eac off-sta rrent th re than ed 1 sec itions c itching.	at V <sub>I</sub> th inp ate ou at cl one o ond. of GND	its shall to the s	e float or V <sub>IH</sub> selected ent. roximate be tes OL	ted minimum d as the es one-H sted at	nalf one
STANDARE MILITARY DF			SIZE A				5962	-89687		

## 查询"5962-8867701XA"保证前 Electrical performance characteristics - Continued

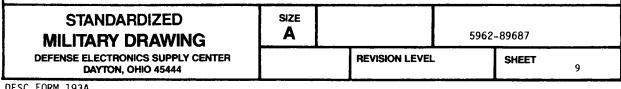
T						
Device t	ype	0	1			
Case out1	ines K	and L	3	1		
Terminal n	umber	Terminal	symbol			
1 2 3 4 5 6 7 8 9 10 10 11 11 12 13 14 15 16 17 17 18 19 20 20 21 22 23 21 22 23 24 25 26 27 28		CAB SAB GAB A1 A2 A3 A4 A5 A6 A7 A8 GND B8 37 36 35 36 35 36 35 31 32 SBA SBA CCC CC CC CC	NC           CAB           SAB           GAB           A1           A2           A3           NC           A4           A5           A6           A7           A8           GND           NC           B8           B7           B6           B5           B4           B3           NC           B2           B1           GBA           CBA           VCC			
NC = No connec	tion					
FIGUF	RE 1. <u>Termina</u>	<u>l connect</u>	ions.			
STANDARDIZED	SIZE					
MILITARY DRAWING	A	1		5962-	-89687	
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		RE	EVISION LEVEL		SHEET	

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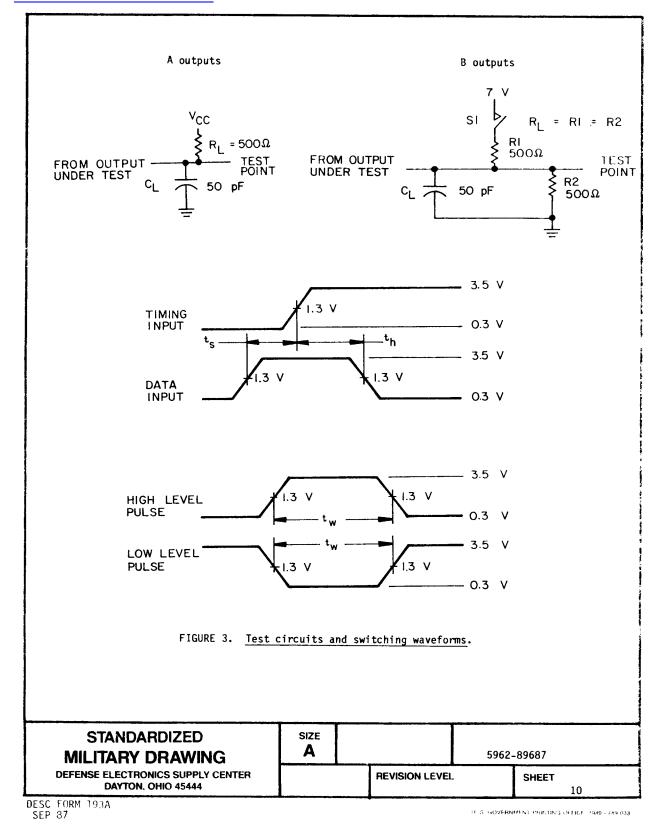
8

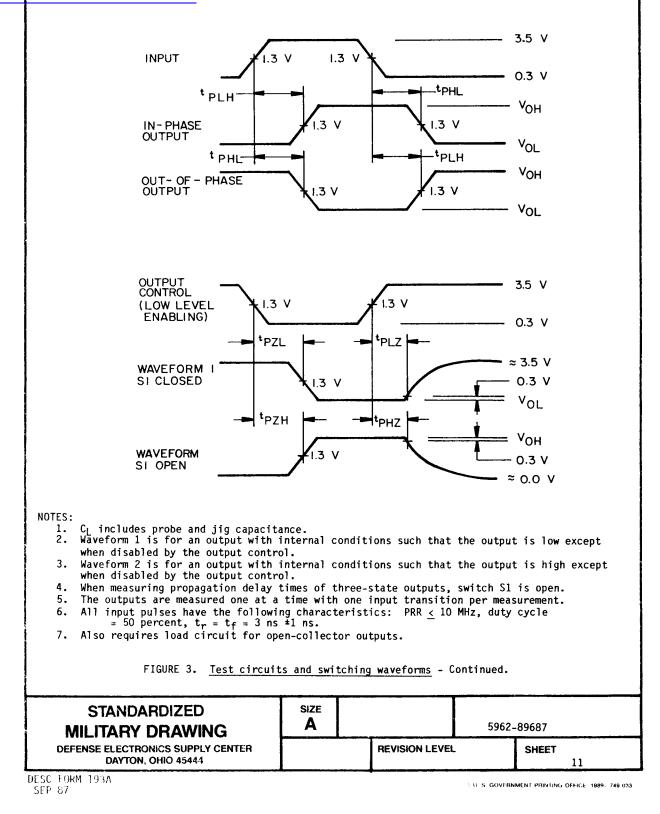
		Inp	uts			Data I	/0	1 Operation or function
GAB	GBA	CAB	CBA	SAB	SBA	A1 thru A8	B1 thru B8	
L	н	H/L	H/L	х	х	   Input	   Input	  Isolation
L	Н	¥	¥	Х	Х	Input	Input	Store A and B data
Х	Н	¥	H/L	X	x	Input	Unspecified	Store A, hold B 
H	H	ŧ	t	X (see note 2)	X	Í Input	Output	Store A in both registers
L	Х	H/L	t	x	x	Unspecified		Hold A, store B
L	L	t	ŧ	x	X (see note 2)	Output	l Input	Store B in both registers
L	L	Х	Х	х	L L	Output	Input	Real-time B data to A bus
L	٤	х	H/L	Х	н	Output	Input	Stored B data to A bus
H	H	Х	х	L	X	Input		Real-time A data to B bus
Н	Н	H/L	X	H	X	Input		Stored A data to B bus
Н	L	H/L	H/L	Н	Н	Output 	Output 	Stored A data to B bus and stored B data to A bus
= L	igh 1 ow 1e High		•	ē	,			
= L /L = = I	ow le High rrele ransi : The inpu on e	or 1 vant tion data ts. very	ow le of cl outpu Data low t	e vel voltage ock from hi t functions input funct o high tran	gh to low may be enab ions are alw sition of th		e., data at t	signals at the GAB or GBA he bus pins will be stored
= L /L = = I = T OTES 1.	ow le High rrele ransi : The inpu on e Sele	or 1 vant tion data ts. very ct co	ow le of cl outpu Data low t ntrol	e vel voltage ock from hi t functions input funct o high tran = L: Cloc	gh to low may be enab ions are alw sition of th ks can occur	ays enable, i.e e clock inputs	e., data at t y.	he bus pins will be stor



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4. QUALITY ASSURANCE PROVISIONS

4.1 Section	Sampling and inspection. Sampling and inspection procedures shall be in accordance with 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
4.2 <u>shall</u> ap	Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be ed on all devices prior to quality conformance inspection. The following additional criter oply:
a.	Burn-in test, method 1015 of MIL-STD-883.
	<ol> <li>Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.6 herein).</li> </ol>
	(2) $T_A = +125^{\circ}C$ , minimum.
b.	Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
method 3	Quality conformance inspection. Quality conformance inspection shall be in accordance with 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional a shall apply.
4.3.1	Group A inspection.
a.	Tests shall be as specified in table II herein.
b.	Subgroups 4, 5, and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
с.	Subgroups 7 and 8 tests shall include verification of the truth table.
4.3.2	Groups C and D inspections.
a.	End-point electrical parameters shall be as specified in table II herein.
b.	Steady-state life test conditions, method 1005 of MIL-STD-883.
	<ol> <li>Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.6 herein).</li> </ol>
	(2) $T_A = +125^{\circ}C$ , minimum.
	(3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

STANDARDIZED MILITARY DRAWING	size A		5962-89687
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	SHEET

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criteria

查询"5962-8867701XA"供应商 TABLE II. <u>Electrical test requirements</u>.

MIL-STD-883 test requirements	Subgroups   (per method   5005, table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	   1*, 2, 3, 7,   8, 9, 10, 11
Group A test requirements (method 5005)	   1, 2, 3, 7,   8, 9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3

\* PDA applies to subgroup 1.

#### 5. PACKAGING

5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-M-38510.

6. NOTES

6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.

6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).

6.4 <u>Record of users</u>. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and the applicable SMD. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DESC-ECC, telephone (513) 296-6022.

6.5 <u>Comments</u>. Comments on this drawing should be directed to DESC-ECC, Dayton, Ohio 45444, or telephone (513) 296-8525.

6.6 <u>Approved sources of supply</u>. Approved sources of supply are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-ECC.

STANDARDIZED MILITARY DRAWING	size A		5962-89687
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL A	SHEET 13
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